

## Micro–macro modelling of stress-dependent anisotropic magnetoresistance

This article has been downloaded from IOPscience. Please scroll down to see the full text article.

2011 J. Phys. D: Appl. Phys. 44 135001

(<http://iopscience.iop.org/0022-3727/44/13/135001>)

View [the table of contents for this issue](#), or go to the [journal homepage](#) for more

Download details:

IP Address: 160.228.216.4

The article was downloaded on 16/03/2011 at 11:52

Please note that [terms and conditions apply](#).

# Micro–macro modelling of stress-dependent anisotropic magnetoresistance

A Bartók, L Daniel and A Razek

Laboratoire de Génie Electrique de Paris (LGEP), CNRS (UMR 8507)-SUPELEC-UPMC Paris 6-Univ Paris-Sud 11, 11 rue Joliot-Curie, Plateau de Moulon, 91192 Gif-sur-Yvette, France

E-mail: [andras.bartok@lgep.supelec.fr](mailto:andras.bartok@lgep.supelec.fr) and [laurent.daniel@u-psud.fr](mailto:laurent.daniel@u-psud.fr)

Received 29 November 2010, in final form 30 January 2011

Published 16 March 2011

Online at [stacks.iop.org/JPhysD/44/135001](http://stacks.iop.org/JPhysD/44/135001)

## Abstract

Anisotropic magnetoresistance (AMR) is the basic phenomenon of a spread class of sensors. AMR effect has a strong mechanical stress dependence. Micromagnetic simulations are often used for modelling the magnetoresistance of ferromagnetic materials, but these approaches do not allow us to investigate macroscopic effects (for example behaviour of a polycrystal under stress) due to the high number of interactions and degrees of freedom. On the other hand macroscopic phenomenological approaches fail in describing the main role of microstructure on the effective behaviour. In this work a micro–macro model is proposed to describe the effect of stress on the AMR in ferromagnetic polycrystals. Results are discussed and compared with experimental data from the literature.

(Some figures in this article are in colour only in the electronic version)

## Introduction

The anisotropic magnetoresistance (AMR) effect in ferromagnetic materials (FM) was first discovered by William Thomson in 1857. Due to its high sensitivity and flexibility of design it is still used in a wide array of sensors for measurement of Earth's magnetic field (electronic compass) [1], for electrical current measuring (by measuring the magnetic field created around the conductor) [2], for traffic detection [3] and for linear position and angle sensing [4].

The electrical resistivity in FM depends on the angle between the direction of electrical current and orientation of the magnetization in the material. This anisotropic dependence lies in spin–orbit coupling. It is fundamentally related to the larger probability of s–d scattering for electrons travelling parallel to the magnetization [5]. As the magnetization rotates, the electron cloud about each nucleus deforms slightly and this deformation changes the amount of scattering undergone by the conduction electrons in their passage through the lattice [6]. Thus the AMR effect is strongly dependent on the local magnetization in the material. In that sense it has some similarities with the magnetostriction effect as discussed later in this paper. On the other hand, owing to the magnetic domain

structure of FM, the distribution of magnetization within FM is very heterogeneous. This is the reason why numerical models for AMR effect are mostly based on micromagnetic calculations [7–9]. In these approaches the number of degrees of freedom and interactions are growing quickly with the number of magnetic moments, so that these simulations can only address small volumes corresponding to a limited number of domains. If the effect of the microstructure on the overall AMR properties is to be investigated—for example the effect of crystallographic texture in polycrystalline media—these methods are not relevant.

It is also known that the AMR effect has a strong mechanical stress dependence [10]. Indeed mechanical stress applied to a magnetic media changes the distribution of domain orientations. As a consequence it modifies the local resistivity, and thus the overall resistivity. This effect of stress on magnetoresistance is for instance used as the basis for a particular type of strain measurement gauges [11].

Some macroscopic phenomenological models for AMR effect have also been proposed [12–14] but they cannot account for microstructure or composition related effects. They have to be identified on macroscopic measurements and cannot be used as predictive tools for material design.

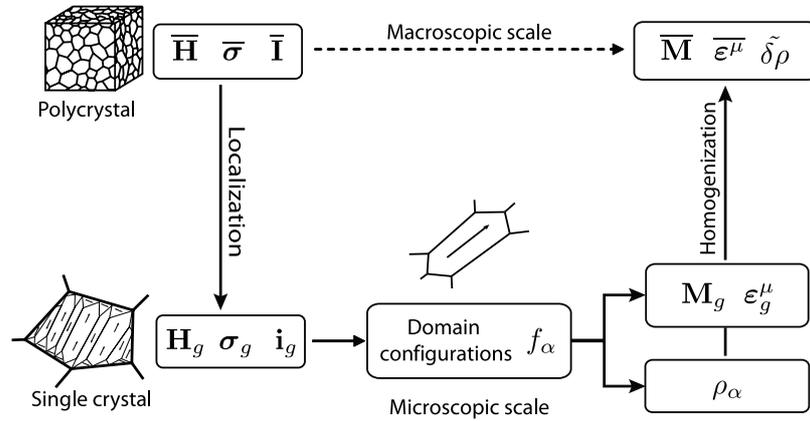


Figure 1. Modelling strategy.

An intermediate approach, standing between micro-magnetic and macroscopic modelling, would be useful in order to provide a design tool sensitive to complex microstructural effects, and notably accounting for the crystallographic texture. Indeed this microstructural parameter can be controlled and significantly modifies the overall AMR properties of FM. In this work a micro-macro model for stress-dependent AMR is proposed. This model is based on a magneto-elastic multiscale model allowing the definition of the local stress and magnetic field in heterogeneous materials from the knowledge of the macroscopic loading. A phenomenological law for AMR effect is then used at the local scale. A homogenization step is finally performed to define the macroscopic change in resistivity. This model can naturally account for the effect of stress on the overall AMR effect, and includes the influence of microstructural parameters such as the crystallographic texture.

The paper is divided into three parts. In the first part the micro-macro model is detailed. In the second part the approach is validated thanks to experimental measurements on iron, nickel and permalloy polycrystals taken from the literature. The approach is finally applied in the third part to the investigation of the effect of crystallographic texture on AMR.

### 1. Micro-macro modelling

AMR effect depends on the local magnetization orientation, itself depending on local magnetic field and stress (at the magnetic domain scale). Owing to the heterogeneity of materials, stress and magnetic field are not uniform within the material. Their local values have to be determined through an appropriate micro-macro scheme. Once these values for the local loading are known, the magnetic domain structure has to be determined, in order to define the local magnetization (at the domain scale). A model for the AMR effect can then be applied. The overall response of the material (polycrystalline scale) is then obtained through appropriate averaging operations. Thus, the model proposed in this paper is based on a three-scale description (polycrystal, single crystal, magnetic domain) and follows the scheme presented in figure 1.

The uppermost calculation scale in the model—called macroscopic scale—is the polycrystalline representative volume element (RVE) which is seen as an assembly of single crystals or grains ( $g$ ) with respect to a given orientation function. The intermediate scale—called mesoscopic scale—is the single crystal or grain, that is seen as a collection of magnetic domains ( $\alpha$ ) with given magnetization orientation. The lowest scale—called microscopic scale—is the magnetic domain, that is an area with uniform magnetostriction strain<sup>1</sup> and magnetization.

The main steps of this model are divided as follows.

- (i) The localization steps aims at defining the local loading (magnetic field  $H_\alpha$ , stress  $\sigma_\alpha$  and current  $i_\alpha$ ) at the microscopic scale as a function of the macroscopic loading (magnetic field  $\bar{H}$ , stress  $\bar{\sigma}$  and current  $\bar{I}$ ). The loading at the mesoscopic scale (magnetic field  $H_g$ , stress  $\sigma_g$  and current  $i_g$ ) is calculated as an intermediate step. These localization steps highly depend on the microstructure of the material.
- (ii) The microscopic magneto-elastic model allows us to define in a statistical way the domain configuration, introducing as an internal variable the volumetric fraction  $f_\alpha$  of domains with orientation  $\alpha$  in a grain  $g$ . In each domain, depending on the considered orientation  $\alpha$ , the magnetization  $M_\alpha$  and magnetostriction strain  $\epsilon_\alpha^\mu$  are known.
- (iii) The microscopic AMR model allows us to define the local resistivity ( $\rho_\alpha$ ) depending on the magnetization orientation  $\alpha$  in the considered domain.
- (iv) The homogenization step allows us to retrieve the overall response of the material at the polycrystal scale (magnetization at the macroscopic scale  $\bar{M}$ , macroscopic magnetostriction strain  $\bar{\epsilon}^\mu$  and the variation of the macroscopic resistivity  $\bar{\delta}\rho$ ) depending on the local values of the response at the microscopic scale.

These steps are detailed hereafter. The magneto-elastic part of the model is based on a reversible magneto-elastic model previously published [15, 16].

<sup>1</sup> Magnetostriction strain is the spontaneous strain undertaken by magnetic materials.

**Table 1.** Physical constants used for the modelling.

| Coefficient                                | $M_S$              | $K_1, K_2$         | $\lambda_{100}, \lambda_{111}$  | $A_s$                      | $C_{11}, C_{12}, C_{44}$ |
|--------------------------------------------|--------------------|--------------------|---------------------------------|----------------------------|--------------------------|
| Unit                                       | $\text{A m}^{-1}$  | $\text{kJ m}^{-3}$ | —                               | $\text{m}^3 \text{J}^{-1}$ | GPa                      |
| Iron [6, 10, 24]                           | $1.71 \times 10^6$ | 42.7, 15           | 21, $-21 (\times 10^{-6})$      | 0.0020                     | 238, 142, 232            |
| Nickel [10, 25]                            | $4.91 \times 10^5$ | $-5.7, -2.3$       | $-45.9, -24.3 (\times 10^{-6})$ | 0.016                      | 250, 160, 118            |
| Fe <sub>11</sub> Ni <sub>89</sub> [10, 26] | $7.50 \times 10^5$ | $-1, -2$           | $-15, -10 (\times 10^{-6})$     | 0.032                      | 243, 148, 122            |

### 1.1. Localization step

The simplest assumption to define the microscopic loading ( $\mathbf{H}_\alpha, \boldsymbol{\sigma}_\alpha, \mathbf{i}_\alpha$ ) as a function of the macroscopic loading ( $\overline{\mathbf{H}}, \overline{\boldsymbol{\sigma}}, \overline{\mathbf{I}}$ ) would be to consider uniform field hypotheses. Under such hypotheses the localization rules are very simple ( $\mathbf{H}_\alpha = \overline{\mathbf{H}}, \boldsymbol{\sigma}_\alpha = \overline{\boldsymbol{\sigma}}, \mathbf{i}_\alpha = \overline{\mathbf{I}}$ ). However, due to the heterogeneity of the materials, these assumptions are often inappropriate.

*1.1.1. Macro–meso scale transition.* In a polycrystal the susceptibility from one grain to another can vary very significantly. For instance in pure iron the permeability of a grain can vary up to 70% at 400 A m<sup>-1</sup> or 60% at 2000 A m<sup>-1</sup> depending on its relative orientation with respect to the magnetic field [17]. This heterogeneity results in a significant heterogeneity of the magnetic field within the material. In the case of polycrystals, the self-consistent scheme is known to provide satisfying results. The macro–meso localization rule is written as follows [16]:

$$\mathbf{H}_g = \overline{\mathbf{H}} + \frac{1}{3 + 2\chi^m} (\overline{\mathbf{M}} - \mathbf{M}_g) \quad (1)$$

$\overline{\mathbf{M}}$  and  $\mathbf{M}_g$  are the magnetization, respectively at the macroscopic and mesoscopic scales. In the case of self-consistent hypothesis  $\chi^m$  is the overall magnetic susceptibility of the material.

The elastic response to a given mechanical loading also significantly differs from one grain to another in a polycrystal. As an example in the case of pure iron Young's modulus can vary up to 115% depending on the crystallographic orientation (see the elastic constants in table 1). The self-consistent localization scheme is known to provide satisfying estimates for polycrystalline media [18]. Under such hypotheses, the macro–meso localization rule can be written in the following form [16]:

$$\boldsymbol{\sigma}_g = \mathcal{B}_\sigma : \overline{\boldsymbol{\sigma}} + \mathcal{L}^{\text{inc}} : (\overline{\boldsymbol{\varepsilon}}^\mu - \boldsymbol{\varepsilon}_g^\mu) \quad (2)$$

$\overline{\boldsymbol{\varepsilon}}^\mu$  and  $\boldsymbol{\varepsilon}_g^\mu$  are the magnetostriction strain, respectively, at the macroscopic and mesoscopic scale.  $\mathcal{B}_\sigma$  denotes the so-called concentration tensor and  $\mathcal{L}^{\text{inc}}$  is a tensor accounting for elastic incompatibilities due to magnetostriction. The way to calculate these fourth order tensor can be found in [18, 16] and is briefly recalled in the appendix.

In the case of the electrical resistivity, and as will be shown in the following, the heterogeneity is weak. Depending on the orientation of the single crystal, the electrical resistivity does not vary more than a few percent. This is why we applied uniform electric current conditions.

$$\mathbf{i}_g = \overline{\mathbf{I}}. \quad (3)$$

*1.1.2. Meso–micro scale transition.* In the case of the localization rules from the grain to the domain scale, an accurate definition of the microstructure, namely the magnetic domain structure, would be requisite<sup>2</sup>. This information is unknown. For the sake of simplicity we assumed uniform magnetic field, uniform strain and uniform current within the single crystal. However in the proposed microscopic magneto-elastic model, the mean values at the single crystal scale are often sufficient data.

### 1.2. Microscopic magneto-elastic model

The magneto-elastic model for the single crystal is derived from [15]. The single crystal is seen as an assembly of magnetic domains. The potential energy of a domain  $\alpha$  is written:

$$W_\alpha = W_\alpha^K + W_\alpha^\sigma + W_\alpha^H \quad (4)$$

where  $W_\alpha^K$  denotes the magnetocrystalline energy,  $W_\alpha^\sigma$  denotes the elastic energy and  $W_\alpha^H$  denotes the magneto-static energy.

In the case of cubic crystallographic structure the magnetocrystalline energy can be written

$$W_\alpha^K = K_1(\alpha_1^2\alpha_2^2 + \alpha_2^2\alpha_3^2 + \alpha_3^2\alpha_1^2) + K_2(\alpha_1^2\alpha_2^2\alpha_3^2) \quad (5)$$

where  $K_1$  and  $K_2$  denote the magnetocrystalline anisotropy constants of the cubic crystal and  $\boldsymbol{\alpha} = {}^t[\alpha_1\alpha_2\alpha_3]$  the direction cosines of the magnetization ( $\mathbf{M}_\alpha = M_s \boldsymbol{\alpha}$  with  $M_s$  the saturation magnetization of the material).

Under uniform strain hypotheses the elastic energy can be written [16]:

$$W_\alpha^\sigma = -\boldsymbol{\sigma}_g : \boldsymbol{\varepsilon}_\alpha^\mu \quad (6)$$

In the case of cubic crystallographic symmetry, the magnetostriction strain tensor  $\boldsymbol{\varepsilon}_\alpha^\mu$  can be written as

$$\boldsymbol{\varepsilon}_\alpha^\mu = \frac{3}{2} \begin{pmatrix} \lambda_{100}(\alpha_1^2 - \frac{1}{3}) & \lambda_{111}\alpha_1\alpha_2 & \lambda_{111}\alpha_1\alpha_3 \\ \lambda_{111}\alpha_1\alpha_2 & \lambda_{100}(\alpha_2^2 - \frac{1}{3}) & \lambda_{111}\alpha_2\alpha_3 \\ \lambda_{111}\alpha_1\alpha_3 & \lambda_{111}\alpha_2\alpha_3 & \lambda_{100}(\alpha_3^2 - \frac{1}{3}) \end{pmatrix} \quad (7)$$

where  $\lambda_{100}$  and  $\lambda_{111}$  are the magnetostrictive constants of the single crystal.

The magneto-static energy of a domain is written as

$$W_\alpha^H = -\mu_0 \mathbf{M}_\alpha \cdot \mathbf{H}_\alpha \quad (8)$$

where  $\mu_0$  is the vacuum permeability.

We then introduce the volumetric fractions  $f_\alpha$  of domains with magnetization orientation  $\boldsymbol{\alpha}$  [16, 19–21]. These internal

<sup>2</sup> Except for the electric current since the hypotheses of weak heterogeneity of the resistivity are still valid.

variables are obtained through the numerical integration of the following Boltzmann-type relation [15]:

$$f_\alpha = \frac{\exp(-A_s \cdot W_\alpha)}{\int_\alpha \exp(-A_s \cdot W_\alpha) d\alpha} \quad (9)$$

where  $A_s$  is an adjustable parameter that can be deduced from low field measurement of the anhysteretic magnetization curve [16] ( $A_s = 3\chi_0/\mu_0 M_s^2$  where  $\chi_0$  is the initial anhysteretic susceptibility of the material).

The magnetostriction strain and the magnetization over the single crystal are defined by an averaging operation over the single crystal (volume  $V_g$ ):

$$\varepsilon_g^\mu = \langle \varepsilon^\mu \rangle_g = \frac{1}{V_g} \int_{V_g} \varepsilon^\mu dV = \sum_\alpha f_\alpha \varepsilon_\alpha^\mu \quad (10)$$

$$\mathbf{M}_g = \langle \mathbf{M} \rangle_g = \frac{1}{V_g} \int_{V_g} \mathbf{M} dV = \sum_\alpha f_\alpha \vec{M}_\alpha. \quad (11)$$

If needed, the elastic strain  $\varepsilon_g^e$  in the single crystal can be easily calculated from Hooke's law (equation (12)) using the single crystal stiffness tensor  $\mathcal{C}_g$ . This elastic strain is superimposed to the magnetostriction strain to obtain the total strain of the single crystal ( $\varepsilon = \varepsilon^e + \varepsilon^\mu$ ).

$$\varepsilon_g^e = \mathcal{C}_g^{-1} : \sigma_g. \quad (12)$$

At this stage, the macroscopic magnetization and magnetostriction strain could also be calculated thanks to an averaging operation over the whole volume of the RVE.

### 1.3. Single-domain model of AMR

Let  $\beta = {}^t[\beta_1 \beta_2 \beta_3]$  be the direction cosines determining the orientation of the current used for measuring the electrical resistance ( $\alpha = {}^t[\alpha_1 \alpha_2 \alpha_3]$  are still the direction cosines of the magnetization in the considered domain). The general expression for the magnetoresistance in any direction of a cubic crystal can be written in a series form of  $\alpha$  and  $\beta$  [13]. Döring used the following form [10] for cubic crystals with negative magnetocrystalline anisotropy constant<sup>3</sup>  $K_1$  (such as nickel and Fe<sub>11</sub>Ni<sub>89</sub> permalloy):

$$\begin{aligned} \rho_\alpha = \rho_0 & \left[ 1 + k_1(\alpha_1^2 \beta_1^2 + \alpha_2^2 \beta_2^2 + \alpha_3^2 \beta_3^2 - \frac{1}{3}) \right. \\ & + 2k_2(\alpha_1 \alpha_2 \beta_1 \beta_2 + \alpha_2 \alpha_3 \beta_2 \beta_3 + \alpha_3 \alpha_1 \beta_3 \beta_1) + k_3 \left( s - \frac{1}{3} \right) \\ & + k_4(\alpha_1^4 \beta_1^2 + \alpha_2^4 \beta_2^2 + \alpha_3^4 \beta_3^2 + \frac{2s}{3} - \frac{1}{3}) + 2k_5(\alpha_1 \alpha_2 \beta_1 \beta_2 \alpha_3^2 \\ & \left. + \alpha_2 \alpha_3 \beta_2 \beta_3 \alpha_1^2 + \alpha_3 \alpha_1 \beta_3 \beta_1 \alpha_2^2) \right] \quad (13) \end{aligned}$$

in which  $s = \alpha_1^2 \alpha_2^2 + \alpha_2^2 \alpha_3^2 + \alpha_3^2 \alpha_1^2$ ,  $\rho_0$  is the resistivity in the demagnetized state and  $k_1, k_2, k_3, k_4, k_5$  are material constants. For a crystal with positive magnetocrystalline anisotropy constant<sup>4</sup>  $K_1$  (such as iron) the expression is the same except that the term  $k_3/3$  is absent.

<sup>3</sup> In that case easy magnetization directions are (111) directions.

<sup>4</sup> In that case easy magnetization directions are (100) directions.

### 1.4. Effective properties

The macroscopic magnetization and strain are obtained through an averaging operation over the whole volume  $V$  of the RVE.

$$\overline{\mathbf{M}} = \langle \mathbf{M} \rangle_V = \langle \mathbf{M}_g \rangle_V \quad (14)$$

$$\overline{\varepsilon} = \langle \varepsilon \rangle_V = \langle \varepsilon^e + \varepsilon^\mu \rangle_V = \langle \varepsilon_g \rangle_V. \quad (15)$$

If needed, the macroscopic magnetostriction strain can be obtained using the following relation [16]:

$$\overline{\varepsilon}^\mu = \langle {}^t \mathcal{B}_\sigma : \varepsilon^\mu \rangle_V = \langle {}^t \mathcal{B}_\sigma : \varepsilon_g^\mu \rangle_V \quad (16)$$

Since the local electric conductivity  $\varsigma_\alpha$  in a domain is known ( $\varsigma_\alpha = 1/\rho_\alpha$ ), the effective macroscopic conductivity  $\tilde{\varsigma}$  can be obtained through a self-consistent approach, applying the classical Bruggeman relation [17, 22, 23].  $\tilde{\varsigma}$  is solution of equation (17) that can be solved easily using a fixed point method.

$$\tilde{\varsigma} = \left\langle \frac{\varsigma_\alpha}{2\tilde{\varsigma} + \varsigma_\alpha} \right\rangle_V = \left\langle \frac{1}{2\tilde{\varsigma} + \varsigma_\alpha} \right\rangle_V \quad (17)$$

where the operation  $\langle \cdot \rangle_V$  is an averaging operation over the whole volume of the RVE. The effective resistivity  $\tilde{\rho}$  is deduced from the effective conductivity ( $\tilde{\rho} = 1/\tilde{\varsigma}$ ). In the following the variation of the macroscopic resistivity  $\tilde{\delta\rho}$  (equation (18)) will be plotted. It can be noticed from equations (13) and (17) that  $\tilde{\delta\rho}$  does not depend on the value of  $\rho_0$ .

$$\tilde{\delta\rho} = \frac{\tilde{\rho} - \rho_0}{\rho_0}. \quad (18)$$

## 2. Validation on isotropic polycrystals

The proposed micro-macro approach has been validated on isotropic iron, nickel and permalloy (Fe<sub>11</sub>Ni<sub>89</sub>) polycrystals.

### 2.1. Model parameters

The mechanical and magnetic characteristics of iron, nickel and a permalloy (Fe<sub>11</sub>Ni<sub>89</sub>) single crystal were used<sup>5</sup> for the calculations. At the single crystal scale, for the calculation of the volumetric fractions  $f_\alpha$ , a 10242 orientation ( $\alpha$ ) data file was used [15]. The material constants are defined in tables 1 and 2. The distribution function for crystal orientation in the case of isotropic polycrystals has been obtained by a regular zoning of the crystallographic space [16]. The corresponding pole figures are given in figure 2.

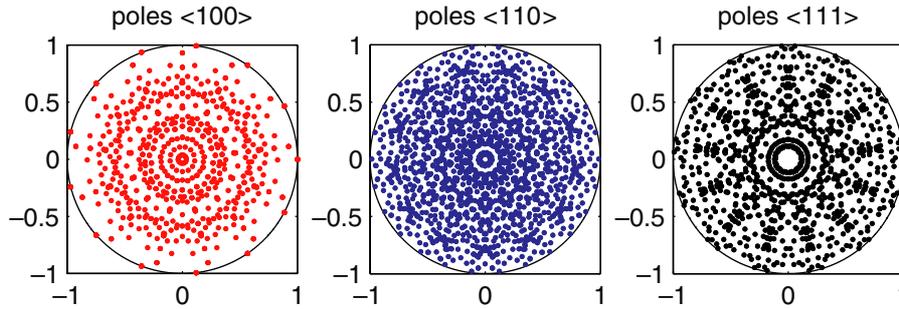
### 2.2. Prediction of the AMR effect

The similarity in the phenomena of magnetostriction and magnetoresistance has been known for a long time. This similarity is linked to the strong dependence of both phenomena on the local magnetization state and thus on the magnetic domain configuration. Our model is based on a

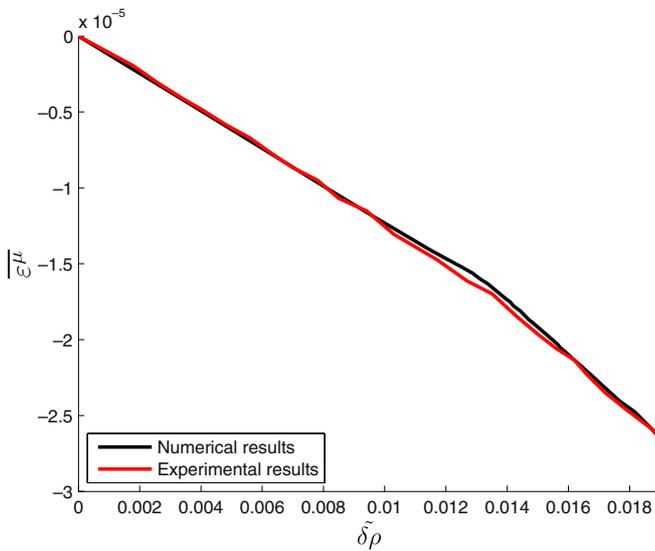
<sup>5</sup> The accurate data of the constants of Döring expression of Fe<sub>11</sub>Ni<sub>89</sub> were not found. The constants of the Fe<sub>15</sub>Ni<sub>85</sub> permalloy were used instead.

**Table 2.** Constants of Döring expression.

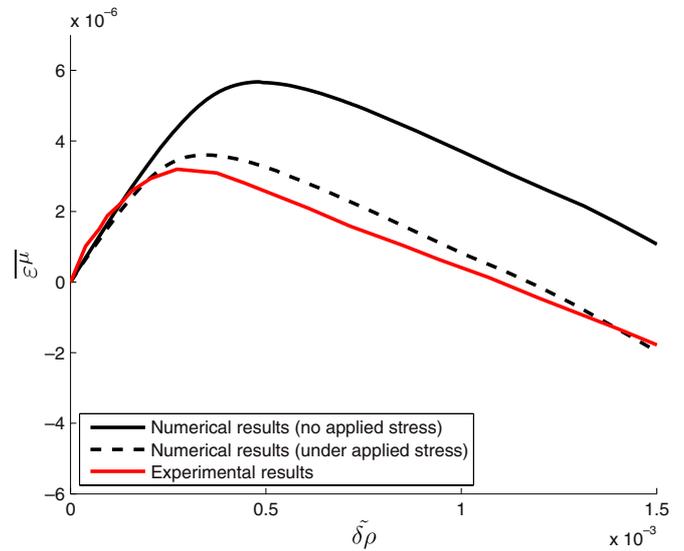
| Coefficient                            | $k_1$   | $k_2$   | $k_3$   | $k_4$   | $k_5$   |
|----------------------------------------|---------|---------|---------|---------|---------|
| Iron [10]                              | 0.00153 | 0.00593 | 0.00194 | 0.00053 | 0.00269 |
| Nickel [10]                            | 0.0654  | 0.0266  | -0.032  | -0.054  | 0.020   |
| Fe <sub>15</sub> Ni <sub>85</sub> [27] | 0.0518  | 0.0478  | -0.0243 | -0.0139 | 0.0259  |



**Figure 2.** Pole figures for an isotropic polycrystal obtained from a regular zoning of the crystallographic space.



**Figure 3.** Magnetostriction strain of nickel polycrystal as a function of the change of resistivity (current and applied magnetic field are parallel)—experimental data [10] and obtained numerical results.



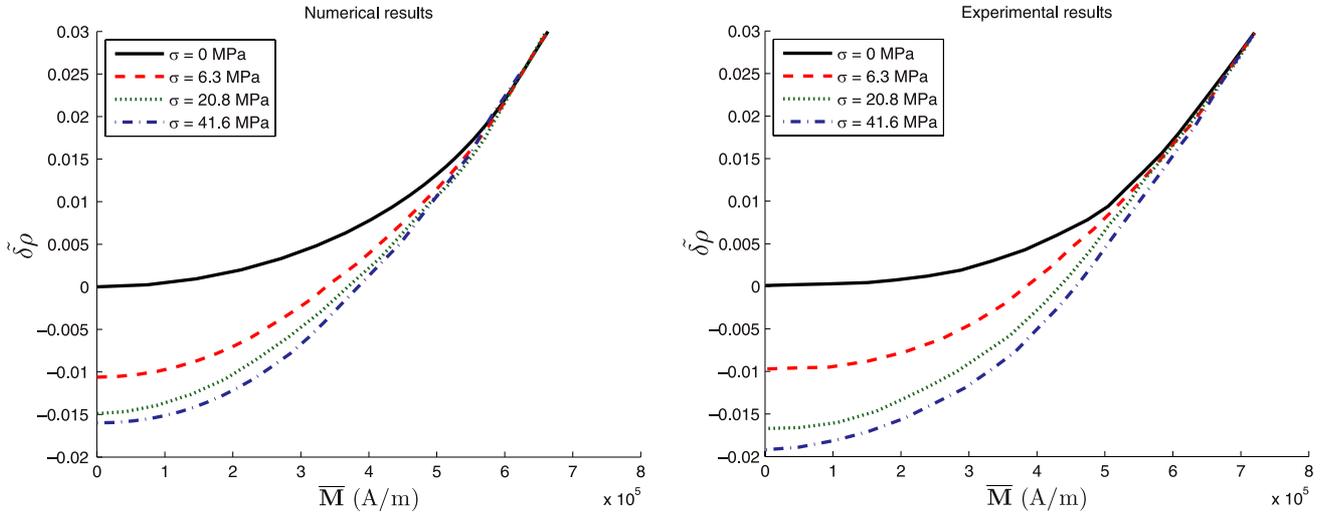
**Figure 4.** Magnetostriction strain of iron polycrystal as a function of the change of resistivity (current and applied magnetic field are parallel)—experimental data [10] and obtained numerical results (dashed line: under 25 MPa tension applied in the direction of magnetic field).

micro-macro approach of the magneto-elastic behaviour of the materials which can give the magnetostriction ( $\lambda(H)$ ) and the magnetoresistance curves ( $\delta\rho(H)$ ). From these results the relation between the change in resistivity and the magnetostriction strain can be easily obtained. It is illustrated in the case of isotropic nickel and pure iron polycrystals without external stress and compared with experimental data from the literature [10] in figures 3 and 4. These figures plot the effective magnetostriction strain as a function of the effective change in resistivity for parallel configuration (magnetic field and electrical current are parallel). Experimental observations show that magnetostriction strain first increases with magnetoresistance and then decreases in the case of iron, and magnetostriction decreases continuously in the case of nickel. The different behaviour of these materials results from the different sign in their material constants (magnetostriction and Döring expression). The experimental curve is accurately

predicted by the model in the case of nickel. The experimental curve for iron is qualitatively predicted, but quantitatively overestimated. It is shown by the dot plot in figure 4 that a macroscopic tension of amplitude 25 MPa applied in the direction of the magnetic field provides a numerical result closer to the experimental observation. This point shows that a residual stress in the material could explain the discrepancies in the case of the iron specimen.

### 2.3. Prediction of the effect of stress on the AMR

In order to study the effect of an applied uniaxial stress on the magnetoresistance, modelling results were compared with experimental results [10] on a permalloy (Fe<sub>11</sub>Ni<sub>89</sub>) polycrystal. In this case the  $\delta\rho(B)$  curves were calculated



**Figure 5.** Change in resistivity (current and applied magnetic field are parallel) with change in magnetization of permalloy polycrystals (Fe<sub>11</sub>Ni<sub>89</sub>), effect of the level of applied uniaxial stress (compression)—obtained numerical results (left) and experimental data [10] (right).

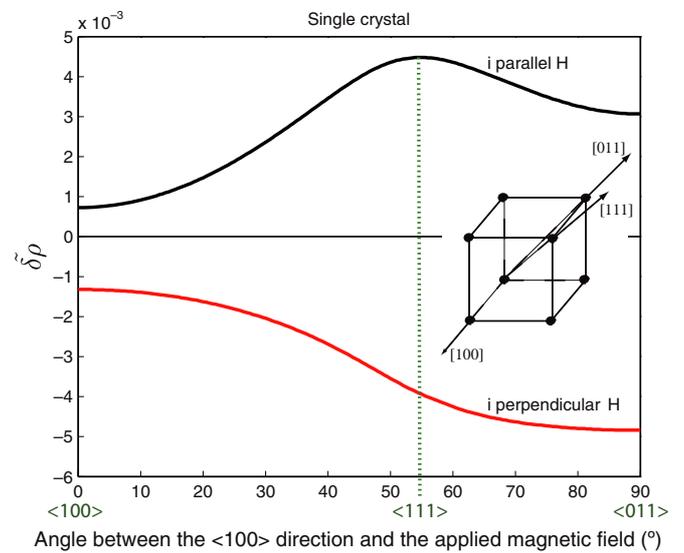
from the combination of  $B(H)$  and  $\tilde{\delta\rho}(H)$  modelling results. This permalloy has negative magnetostriction so that the tension orients its domains perpendicularly to the direction of tension and this effect decreases the initial resistivity. The comparison between numerical and experimental results (figure 5) gives very satisfying results. It shows the nonlinear stress dependence as well. The stress decreases the initial resistivity and increases the slope of the curves which is important in the sensor application (higher sensibility in low field measurement). The model can predict the effect of a multiaxial stress as well but these results are not presented in this paper due to the lack of experimental results for validation.

### 3. Investigation of crystallographic texture effect

The magnetoresistance in a single crystal is strongly anisotropic. Figure 6 shows the change in resistivity in a pure iron single crystal as a function of the angle between its easy magnetization direction  $\langle 100 \rangle$  and the applied magnetic field in the  $\{011\}$  crystallographic plane. The change in resistivity (under no applied stress) can vary up to several hundred percent depending on the orientation of the magnetic field with respect to the crystal orientation, both in parallel and perpendicular configurations. As a consequence, the AMR effect can be expected to be very sensitive to crystallographic texture.

In order to investigate this effect, the crystallographic texture of an Armco specimen (pure iron), known as isotropic, has been obtained from electron back-scattered diffraction (EBSD) measurement. The corresponding pole figures are given in figure 7. It shows a weak texture compared with the calculated isotropic crystal orientation distribution used previously and showed in figure 2.

The prediction of the AMR effect for pure iron using this latter crystallographic texture has been compared with the prediction using the isotropic orientation data file. Figure 8 shows the change in resistivity in the parallel current/applied magnetic field configuration as a function of current orientation in the polycrystal. In the case of Armco specimen two planes ( $XY$  and  $YZ$ ) have been investigated.



**Figure 6.** Change in resistivity as a function of the angle between the  $\langle 100 \rangle$  direction and the applied magnetic field ( $10^5 \text{ A m}^{-1}$ ) in the  $\{011\}$  crystallographic plane—pure iron single crystal in parallel (parallel magnetic field and electrical current) and perpendicular (perpendicular magnetic field and electrical current) configurations.

It is shown that even for this very weakly textured material the magnetoresistance can vary up to 10% depending on the orientation of the solicitation (parallel configuration). The magnetoresistance is confirmed to be strongly dependent on crystallographic texture.

### 4. Conclusion

A micro–macro model for the effect of stress on the anisotropic magnetoresistance has been presented. It is based on a description of the magneto-mechanical coupling at several scales (domain, single crystal, polycrystal). The behaviour of iron, nickel and a permalloy (Fe<sub>11</sub>Ni<sub>89</sub>) polycrystal has been calculated. Numerical results have been compared with experimental results from the literature with very satisfying

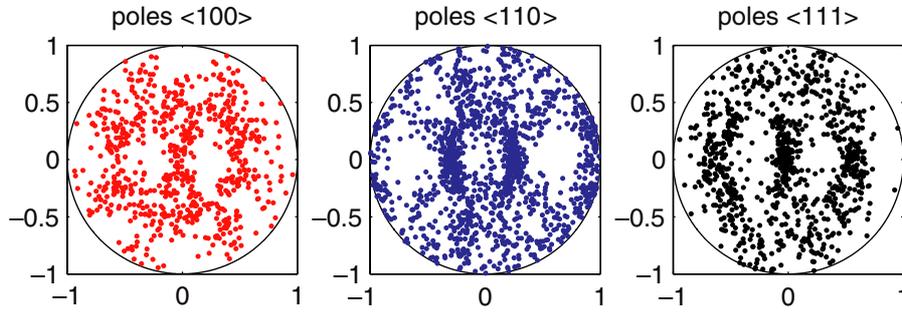


Figure 7. Pole figures of an Armco steel obtained from EBSD measurement.

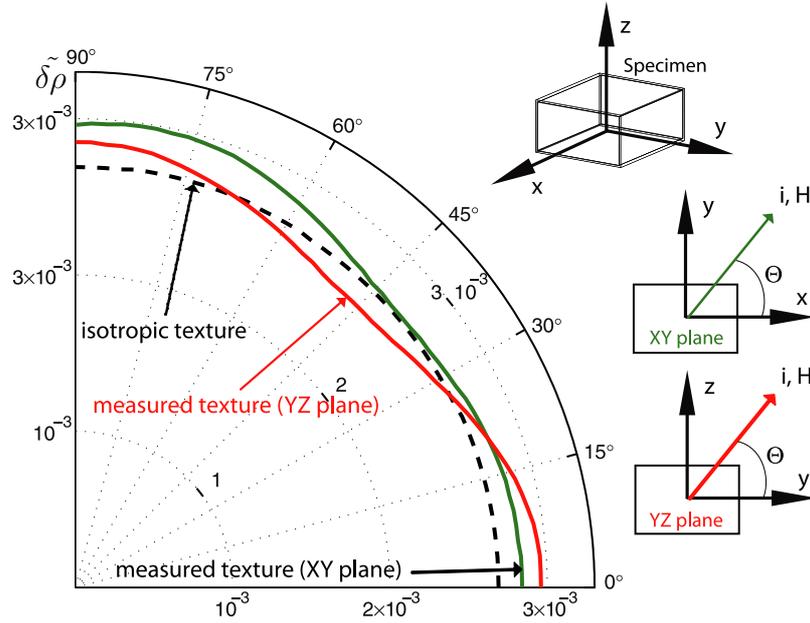


Figure 8. Change in resistivity (current and applied magnetic field are parallel) with change in the orientation of the applied magnetic field ( $10^5 \text{ A m}^{-1}$ ) for pure iron polycrystal using an isotropic texture (dotted line) and texture data from EBSD measurement in different planes (lines).

agreement. This model enables us to investigate the effect of crystallographic texture on AMR effect and it highlights the strong influence of crystallographic texture on it. It also enables us to investigate the effect of stress, and notably multiaxial stress on magnetoresistance. The development of micro–macro models accounting for microstructure and stress dependence of effective magnetoresistive properties should allow the design of high precision AMR devices.

### Acknowledgments

The authors are greatly indebted to Dr Anne-Laure Helbert (ICMMO, Univ Paris-Sud) for the EBSD measurement of the Amrco steel.

### Appendix. Calculation of mechanical localization operators

We briefly give hereafter the way to obtain the fourth order tensors  $B_\sigma$  and  $\mathcal{L}^{\text{inc}}$  appearing in section 1.1. More detailed explanations can be found in [16, 18].

$B_\sigma$  is defined by equation (19) that introduces the single crystal stiffness tensor  $C_g$ , the polycrystal effective stiffness tensor  $\tilde{C}$  and the strain localization tensor  $\mathcal{A}_\sigma$ .

$$B_\sigma = C_g : \mathcal{A}_\sigma : \tilde{C}^{-1}. \quad (19)$$

$\mathcal{A}_\sigma$  is defined by equation (21) where  $C^*$  is the so-called Hill constraint tensor [18] that can be obtained from the Eshelby tensor  $S^E$  according to equation (21),  $\mathcal{I}$  being the fourth order identity tensor.

$$\mathcal{A}_\sigma = (C_g + C^*)^{-1} : (\tilde{C} + C^*) \quad (20)$$

$$C^* = \tilde{C} : (S^{E-1} - \mathcal{I}). \quad (21)$$

$\mathcal{L}^{\text{inc}}$  is defined by equation (22).

$$\mathcal{L}^{\text{inc}} = C_g : (C_g + C^*)^{-1} : C^*. \quad (22)$$

### References

- [1] Vcelak J, Ripka P, Kubik J, Platil A and Kaspar P 2005 AMR navigation systems and methods of their calibration *Sensors Actuators A* **123–124** 122

- [2] Mlejnek P, Vopalensky M and Ripka P 2008 AMR current measurement device *Sensors Actuators A* **141** 649
- [3] Application Note 2005 Vehicle detection and compass applications using AMR magnetic sensors *Technical Report AN218*, Honeywell SSEC, [www.ssec.honeywell.com](http://www.ssec.honeywell.com)
- [4] Adelerhof D J and Geven W 2000 New position detectors based on AMR sensors *Sensors Actuators* **85** 48
- [5] Smit J 1951 Magnetoresistance of ferromagnetic metals and alloys at low temperatures *Physica* **17** 612
- [6] Cullity B D 1972 *Introduction to Magnetic Materials* (London: Addison-Wesley)
- [7] Adeyeye A O and White R L 2004 Magnetoresistance behavior of single castellated Ni<sub>80</sub>Fe<sub>20</sub> nanowires *J. Appl. Phys.* **95** 2025
- [8] Hafner M *et al* 2009 Theory of anisotropic magnetoresistance in atomic-sized ferromagnetic metal contacts *Phys. Rev. B* **79** 140410(R)
- [9] Serrano-Guisan S, Rott K, Reiss G and Schumacher H W 2008 Inductive and magneto-resistive measurements of gilbert damping in Ni<sub>81</sub>Fe<sub>19</sub> thin films and microstructures *J. Phys. D: Appl. Phys.* **41** 164015
- [10] Bozorth R M 1951 *Ferromagnetism* (Princeton, NJ: Van Nostrand)
- [11] Sonehara M, Shinohara M, Sato T, Yamasawa T and Miura K 2010 Strain sensor using stress-magnetoresistance effect of NiFe/MnIr exchange-coupled magnetic film *J. Appl. Phys.* **107** 09E718
- [12] Kwiatkowski W, Stabrowski M and Tumanski S 1983 Numerical analysis of the shape anisotropy and anisotropy dispersion in thin film permalloy magnetoresistors *IEEE Trans. Magn.* **MAG-19** 2502
- [13] McGuire T R and Potter R I 1975 Anisotropic magnetoresistance in ferromagnetic 3d alloys *IEEE Trans. Magn.* **11** 1018
- [14] Li J, Li S L, Wu Z W, Li S, Chu H F, Wang J, Zhang Y, Tian H Y and Zheng D N 2010 A phenomenological approach to the anisotropic magnetoresistance and planar hall effect in tetragonal La<sub>2/3</sub>Ca<sub>1/3</sub>MnO<sub>3</sub> thin films *J. Phys.: Condens. Matter* **22** 146006
- [15] Daniel L and Galopin N 2008 A constitutive law for magnetostrictive materials and its application to Terfenol-d single and polycrystals *Eur. Phys. J. Appl. Phys.* **42** 153
- [16] Daniel L, Hubert O, Buiron N and Billardon R 2008 Reversible magneto-elastic behavior: A multiscale approach *J. Mech. Phys. Solids* **56** 1018
- [17] Daniel L and Corcolle R 2007 A note on the effective magnetic permeability of polycrystals *IEEE Trans. Magn.* **43** 3153
- [18] Hill R 1965 Continuum micro-mechanics of elastoplastic polycrystals *J. Mech. Phys. Solids* **13** 213
- [19] Néel L 1944 Les lois de l'aimantation et de la subdivision en domaines élémentaires d'un monocristal de fer *J. Phys. Radiat.* **5** 241
- [20] Chikazumi S 1997 *Introduction to Ferromagnetic Materials* (Reading, MA: Addison-Wesley)
- [21] Buiron N, Hirsinger L and Billardon R 1999 A multiscale model for magneto-elastic couplings *J. Phys. IV* **9** Pr9-187-Pr9-196
- [22] Bruggeman D A G 1935 Berechnung verschiedener physikalischer konstanten von heterogenen substanzen *Annal. Phys. Lpz.* **416** 636
- [23] Stroud D 1975 Generalized effective-medium approach to the conductivity of an inhomogeneous material *Phys. Rev. B* **12** 3368
- [24] McClintock F A and Argon A S 1966 *Mechanical Behavior of Materials* (New York Addison-Wesley)
- [25] Hausch G and Warlimont H 1973 Single crystalline elastic constants of ferromagnetic face centered cubic Fe-Ni invar alloys *Acta Metal.* **21** 401
- [26] Kanrar A and Ghosh U S 1983 The variation of elastic constants of nickel-iron single crystal alloys from 78.76 to 300 K *J. Phys. Chem. Solids* **44** 457-62
- [27] Berger L and Friedberg S A 1968 Magnetoresistance of a permalloy single crystal and effect of 3d orbital degeneracies *Phys. Rev.* **165** 760